Amplifiers and Comparators

In Brief . . .

For over two decades, Motorola has continually refined and updated integrated circuit technologies, analog circuit design techniques and processes in response to the needs of the marketplace. The enhanced performance of newer operational amplifiers and comparators has come through innovative application of these technologies, designs and processes. Some early designs are still available but are giving way to the new, higher performance operational amplifier and comparator circuits. Motorola has pioneered in JFET inputs, low temperature coefficient input stages, Miller loop compensation, all NPN output stages, dual-doublet frequency compensation and analog "in-the-package" trimming of resistors to produce superior high performance operational amplifiers and comparators, operating in many cases from a single supply with low input offset, low noise, low power, high output swing, high slew rate and high gain-bandwidth product at reasonable cost to the customer.

Present day operational amplifiers and comparators find applications in all market segments including motor controls, instrumentation, aerospace, automotive, telecommunications, medical, and consumer products.

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Operational Amplifiers

Motorola offers a broad line of bipolar operational amplifiers to meet a wide range of applications. From low–cost industry–standard types to high precision circuits, the span encompasses a large range of performance capabilities. These Analog integrated circuits are available as single, dual

and quad monolithic devices in a variety of temperature ranges and package styles. Most devices may be obtained in unencapsulated "chip" form as well. For price and delivery information on chips, please contact your Motorola Sales Representative or Distributor.

Table 1. Single Operational Amplifiers

						BW	SR	Sup			
	l _{IB}	V _{IO}	TCVIO	lio	A _{vol}	(A _V = 1)	$(A_V = 1)$	Volt (\	_		
Device	(μ Α) Max	(mV) Max	(μV/°C) Typ	(nA) Max	(V/mV) Min	(MHz) Typ	(V/μs) Typ	Min	Max	Description	Suffix/ Package
Noncomper Commercial		ture Ran	ge (0°C to	+70°C)							
LM301A LM308A	0.25 7.0	7.5 0.5	10 5.0	50 1.0	25 80	1.0 1.0	0.5 0.3	±3.0 ±3.0	±18 ±18	General Purpose Precision	N/626, D/751 N/626, D/751
Industrial Ter	mperatur	e Range	(–25°C to	⊢—— > +85°C)		<u>I</u>			<u> </u>		
LM201A	0.075	2.0	10	10	50	1.0	0.5	±3.0	±22	General Purpose	N/626, D/751
Internally C	•		ma (0°C ta	. 70°C)					•		
Commercial			```		05	4.0	40	15.0	140	IEEE Lamest	N/000 D/754
	200 pA 200 pA	10 2.0	10 10	100 pA 100 pA	25 25	4.0 8.0	13 25	±5.0 +5.0	±18 ±22	JFET Input JFET Input, Low Offset, Low Drift	N/626, D/751 N/626, D/751
MC1436, C	0.04	10	12	10	70	1.0	2.0	±15	±34	High Voltage	P1/626, D/751
MC1741C	0.5	6.0	15	200	20	1.0	0.5	±3.0	±18	General Purpose	P1/626, D/751
MC1776C	0.003	6.0	15	3.0	100	1.0	0.2	±1.2	±18	μPower, Programmable	P1/626, D/751
MC3476	0.05	6.0	15	25	50	1.0	0.2	±1.5	±18	Low Cost, μPower, Programmable	P1/626
	200 pA	10	10	100 pA	25	4.0	13	±5.0	±18	JFET Input	P/626, D/751
	200 pA	5.0	10	100 pA	50	4.0	13	±5.0	±18	JFET Input	P/626, D/751
MC34071	0.5	5.0	10	75	25	4.5	10	+3.0	+44	High Performance	P/626, D/751
	500 nA	3.0	10	50	50	4.5	10	+3.0	+44	Single Supply	P/626, D/751
	200 pA	1.0	10	100 pA	25	16	55	±5.0	±22	Decompensated	P/626, D/751
	200 pA	1.0	10	100 pA	25	8.0	30	±5.0	±22	High Speed, JFET Input	P/626, D/751
MC34181 TL071AC	0.1 nA 200 pA	2.0 6.0	10 10	0.05 50 pA	25 50	4.0 4.0	10 13	±2.5 ±5.0	±18 ±18	Low Power, JFET Input Low Noise, JFET Input	P/626 P/626
	200 pA 200 pA	10	10	50 pA	25	4.0	13	±5.0	±18	Low Noise, JFET Input	D/751
	200 pA	6.0	10	100 pA	50	4.0	13	±5.0	±18	JFET Input	P/626
	400 pA	15	10	200 pA	25	4.0	13	±5.0	±18	JFET Input	D/751
Automotive 7	Tempera	ture Ranç	ge (−40°C	to +85°C)	1					
MC33071	0.5	5.0	10	75	25	4.5	10	+3.0	+44	High Performance	P/626, D/751
	500 nA	3.0	10	50	50	4.5	10	+3.0	+44	Single Supply	P/626, D/751
MC33171	0.1	4.5	10	20	50	1.8	2.1	+3.0	+44	Low Power, Single Supply	P/626, D/751
MC33181	0.1 nA	2.0	10	0.05	25	4.0	10	±2.5	±18	Low Power, JFET Input	P/626, D/751
Extended Ter MC33201	250 nA	9.0	2.0	100°C)	50	2.2	1.0	±0.9	±6.0	Low V Rail-to-Rail	P/626, D/751
Military Temp									1	1	
 	400 nA	9.0	2.0	200	50	2.2	1.0	±0.9	±6.0	Low V Rail-to-Rail	P/626, D/751

Table 2. Dual Operational Amplifiers

Device Internally Com	(μΑ)		TCVIO	lo (A _{vol}	(A _V = 1)	SR (A _V = 1)	Volt	-		Cee:/
	Max	(mV) Max	(μV/°C) Typ	(nA) Max	(V/mV) Min	(MHz) Typ	(V/μs) Typ	Min	Max	Description	Suffix/ Package
	pensate	ed									
Commercial Tem	nperature	Range	(0°C to +	70°C)							
	200 pA	10	10	100 pA	25	4.0	13	±5.0	±18	JFET Input	N/626, D/751
	200 pA	3.0	10	100 pA	25	4.0	13	+5.0	±18	JFET Input, Low Offset, Low Drift	N/626, D/751
I I	100 pA	5.0	10	50 pA	25	2.0	6.0	±5.0	±18	Low Power, JFET Input	N/626
LM358	0.25	6.0	7.0	50	25	1.0	0.6	±1.5 +3.0	±18 +36	Single Supply, Low Power Consumption	N/626, D/751
LM833	1.0	5.0	2.0	200	31.6	15	7.0	+2.5	±18	Low Noise, Audio	N/626, D/751
MC1458	0.5	6.0	10	200	20	1.1	0.8	±3.0	±18	Dual MC1741	P1/626, D/751
MC1458C	0.7	10	10	300	20	1.1	8.0	±3.0	±18	General Purpose	P1/626, D/751
MC3458	0.5	10	7.0	50	20	1.0	0.6	±1.5 +3.0	±18 +36	Split Supplies, Single Supply,	P1/626, D/751
										Low Crossover Distortion	
MC4558AC	0.5	5.0	10	200	50	2.8	1.6	±3.0	±22	High Frequency	P1/626
MC4558C	0.5	6.0	10	200	20	2.8	1.6	±3.0	±18	High Frequency	P1/626, D/751
I I	100 pA	10	10	100 pA	25	4.0	13	±5.0	±18	JFET Input	P/626, D/751
I I	100 pA	5.0	10	70 pA	25	4.0	13	±5.0	±18	JFET Input	P/626, D/751
MC34072	0.5	5.0	10	75 50	25	4.5	10	+3.0	+44	High Performance	P/626, D/751
	500 nA 200 pA	3.0 3.0	10 10	50 100 pA	50 25	4.5 8.0	10 30	+3.0 ±5.0	+44 ±22	Single Supply High Speed, JFET Input	P/626, D/751 P/626
	200 pA 200 pA	3.0	10	100 pA 100 pA	25 25	16	55	±5.0	±22	Decompensated	P/626
I I	0.1 nA	3.0	10	0.05	25	4.0	10	±2.5	±18	Low Power, JFET Input	P/626, D/751
	200 pA	6.0	10	100 pA	4.0	2.0	6.0	±2.5	±18	Low Power, JFET Input	P/626, D/751
	200 pA	15	10	200 pA	4.0	2.0	6.0	±2.5	±18	Low Power, JFET Input	P/626, D/751
I I	200 pA	6.0	10	50 pA	50	4.0	13	±5.0	±18	Low Noise, JFET Input	P/626
TL072C 2	200 pA	10	10	50 pA	25	4.0	13	±5.0	±18	Low Noise, JFET Input	D/751
TL082AC	200 pA	6.0	10	100 pA	50	4.0	13	±5.0	±18	JFET Input	P/626
TL082C	400 pA	15	10	200 pA	25	4.0	13	±5.0	±18	JFET Input	D/751
Industrial Tempe	erature R	ange (–	25°C to +	85°C)							
LM258	0.15	5.0	10	30	50	1.0	0.6	±1.5	±18	Split or Single Supply	N/626, D/751
								+3.0	+36	Op Amp	
Automotive Tem	perature	Range	(-40°C to	+85°C)							
MC3358	5.0	8.0	10	75	20	1.0	0.6	±1.5 +3.0	±18 +36	Split or Single Supply	P1/626
MC33072	0.50	5.0	10	75	25	4.5	10	+3.0	+44	High Performance	P/626, D/751
MC33072A	500 nA	3.0	10	50	50	4.5	10	+3.0	+44	Single Supply	P/626, D/751
MC33076	0.5	4.0	2.0	70	25	7.4	2.6	±2.0	±18	High Output Current	P1/626, P2/648C, D/751
MC33077	1.0	1.0	2.0	180	150	37	11	±2.5	±18	Low Noise	P/626, D/751
MC33078 MC33102	750 nA	2.0	2.0	150	31.6	16	7.0	±5.0	±18	Low Noise	N/626, D/751 P/626, D/751
/ -	600 nA	3.0	1.0	60	25	4.6	1.7	±2.5	±18	Sleep-Mode™	
I I	60 nA	3.0	1.0	6.0	15	0.3	0.1	±2.5	±18	Micropower	
MC33172	0.10	4.5	10	20	50	1.8	2.1	+3.0	+44	Low Power, Single Supply	P/626, D/751
MC33178	0.5	3.0	2.0	50	50	5.0	2.0	±2.0	±18	High Output Current	P/626, D/751
	0.1 nA	3.0	10	0.05	25	4.0	10	±2.5	±18	Low Power, JFET Input	P/626, D/751
	650 nA	1.0	0.56	25 nA	31.6	5.5	11.5	±1.5	±18	High Performance	P/626, D/751
	100 pA	200 μV	5.0	50 pA	50	30	12	±2.5	±18	Low Input, Offset JFET	P/626, D/751
TL062V	200 pA	6.0	10	100 pA	4.0	2.0	6.0	±2.5	±18	Low Power, JFET Input	P/626, D/751

Table 2. Dual Operational Amplifiers (continued)

Device	l _{IB} (μΑ) Max	V _{IO} (mV) Max	TC _{VIO} (μV/°C) Typ	l _{IO} (nA) Max	A _{VOI} (V/mV) Min	BW (A _V = 1) (MHz)	SR (A _V = 1) (V/μs)	Sup Volt (\ Min	age	Description	Suffix/ Package
	1110111			-	IVIIII	Тур	Тур	IVIIII	IVIAX	Description	Fackage
Extended Temp	perature R	tange (–	40°C to +	105°C)							
MC33202	250 nA	11	2.0	100	50	2.2	1.0	±0.9	±6.0	Low V Rail-to-Rail	P/626, D/751
MC33206										Rail–to–Rail with Enable	P/646, D/751A
MC33502	40 fA	0.5	2.0 typ	_	100	4.0 typ	4.0 typ	+0.9	+7.0	1.0 V Rail-to-Rail	P/262, D751
	typ	typ			typ	''	'				
LM2904	0.25	10	7.0	50	100	1.0	0.6	±1.5	±13	Split or Single Supply	N/262, D/751
					typ			+3.0	+26		
Extended Auto	motive Te	mperatu	ıre Range	(−40°C t	o +125°C	;)					
TCA0372	500 nA	15	20	50	30	1.1	1.4	+5.0	+36	Power Op Amp, Single Supply	DP2/648, DW/751G
LM2904V	0.25	13	7.0	50	100	1.0	0.6	±1.5	±13	Split or Single Supply	N/626, D/751
					typ			+3.0	+26		
Military Tempe	rature Rai	nge (–55	°C to +12	5°C)	-	-		-			
MC33202	400 pA	11	2.0	200 pA	50	2.2	1.0	±0.9	±6.0	Low V Rail-to-Rail	P/626, D/751

Table 3. Quad Operational Amplifiers

	l _{IB} (μΑ)	V _{IO} (mV)	TC _{VIO} (μV/°C)	I _{IO} (nA)	A _{VOI} (V/mV)	BW (A _V = 1) (MHz)	SR (A _V = 1) (V/μs)	Sup Volt (\	age		Suffix/
Device	Max	Max	Тур	Max	Min	Тур	Typ	Min	Max	Description	Package
Internally (Compen	sated									
Commercial	Tempera	ture Ran	ge (0°C to	+70°C)							
LF347	200 pA	10	10	100 pA	25	4.0	13	±5.0	±18	JFET Input	N/646
LF347B	200 pA	5.0	10	100 pA	50	4.0	13	±5.0	±18	JFET Input	N/646
LF444C	100 pA	10	10	50 pA	25	2.0	6.0	±5.0	±18	Low Power, JFET Input	N/646, D/751A
LM324, A	0.25	6.0	7.0	50	25	1.0	0.6	±1.5	±16	Low Power	N/646, D/751A
								+3.0	+32	Consumption	
MC3403	0.5	10	7.0	50	20	1.0	0.6	±1.5	±18	No Crossover	P/646, D/751A
								+3.0	+36	Distortion	
MC4741C	0.5	6.0	15	200	20	1.0	0.5	±3.0	±18	Quad MC1741	P/646, D/751A
MC34004	200 pA	10	10	100 pA	25	4.0	13	±5.0	±18	JFET Input	P/646
MC34004B	200 pA	5.0	10	100 pA	50	4.0	13	±5.0	±18	JFET Input	P/646
MC34074	0.5	5.0	10	75	25	4.5	10	+3.0	+44	High Performance	P/646, D/751A
MC34074A	500 nA	3.0	10	50	50	4.5	10	+3.0	+44	Single Supply	P/646, D/751A
MC34084	200 pA	12	10	100 pA	25	8.0	30	±5.0	±22	High Speed, JFET Input	P/646, DW/751G
MC34085B	200 pA	12	10	100 pA	25	16	55	±5.0	±22	Decompensated	P/646, DW/751G
MC34184	0.1 nA	10	10	0.05	25	4.0	10	±2.5	±18	Low Power, JFET Input	P/646, D/751A
TL064AC	200 pA	6.0	10	100 pA	4.0	2.0	6.0	±2.5	±18	Low Power, JFET Input	N/646, D/751A
TL064C	200 pA	15	10	200 pA	4.0	2.0	6.0	±2.5	±18	Low Power, JFET Input	N/646, D/751A
TL074AC	200 pA	6.0	10	50 pA	50	4.0	13	±5.0	±18	Low Noise, JFET Input	N/646
TL074C	200 pA	10	10	50 pA	25	4.0	13	±5.0	±18	Low Noise, JFET Input	N/646
TL084AC	200 pA	6.0	10	100 pA	50	4.0	13	±5.0	±18	JFET Input	N/646
TL084C	400 pA	15	10	200 pA	25	4.0	13	±5.0	±18	JFET Input	N/646
Industrial Te	emperatu	re Range	(−25°C to	+85°C)							
LM224, A	0.15	5.0	7.0	30	50	1.0	0.6	±1.5	±16	Split Supplies or	N/646, D/751A
								+3.0	+32	Single Supply	

Table 3. Quad Operational Amplifiers (continued)

Parida	l _{IB} (μA)	V _{IO} (mV)	TC _{VIO} (μV/°C)	I _{IO} (nA)	A _{VOI} (V/mV)	BW (A _V = 1) (MHz)	SR (A _V = 1) (V/μs)	Sup Volt (\	age /)	Donatical co	Suffix/
Device	Max	Max	Тур	Max	Min	Тур	Тур	Min	Max	Description	Package
Automotive	Tempera	ture Ran	ge (–40°C	to +85°C	5)						
MC3303	0.5	8.0	10	75	20	1.0	0.6	±1.5	±18	Differential	P/646, D/751A
					1			+3.0	+36	General Purpose	
MC33074	0.5	4.5	10	75	25	4.5	10	+3.0	+44	High Performance,	P/646, D/751A
										Single Supply	
MC33074A	500 nA	3.0	10	50	50	4.5	10	+3.0	+44	High Performance	P/646, D/751A
MC33079	750 nA	2.5	2.0	150	31.6	9.0	7.0	±5.0	±18	Low Noise	N/646, D/751A
MC33174	0.1	4.5	10	20	50	1.8	2.1	+3.0	+44	Low Power, Single Supply	P/646, D/751A
MC33179	0.5	3.0	2.0	50	50	5.0	2.0	±2.0	±18	High Output Current	P/646, D/751A
MC33184	0.1 nA	10	10	0.05	25	4.0	10	±2.5	±18	Low Power, JFET Input	P/646, D/751A
MC33274A	650 nA	1.0	0.56	25 nA	31.6	5.5	11.5	±1.5	±18	High Performance	P/646, D/751A
MC33284	100 pA	2.0	5.0	50 pA	50	30	12	±2.5	±18	Low Input, Offset JFET	P/646, D/751A
TL064V	200 pA	9.0	10	100 pA	4.0	2.0	6.0	±2.5	±18	Low Power, JFET Input	N/646, D/751A
Extended Te	emperatu	re Range	(-40°C to	+105°C)							
MC33204	250 nA	13	2.0	100	50	2.2	1.0	±0.9	±6.0	Low V Rail-to-Rail	P/646, D/751A
MC33207					50	2.2		±0.9	±6.0	Rail-to-Rail with Enable	P/648, D/751B
MC33304					25	3.0		+1.8	+12	Sleepmode, Rail-to-Rail	P/646, D/751A
LM2902	0.5	10	_	50	15	1.0	0.6	±1.5	±13	Differential Low Power	N/646, D/751A
								+3.0	+26		
Extended A	utomotive	e Temper	ature Rar	ge (–40°	C to +125	i°C)					
LM2902V	0.5	13	_	50	15	1.0	0.6	±1.5	±13	Differential Low Power	N/646, D/751A
								+3.0	+26		
Military Tem	perature	Range (-	-55°C to +	125°C)							
MC33204	400 pA	13	2.0	200 pA	50	2.2	1.0	±0.9	±6.0	Low V Rail-to-Rail	P/646, D/751A

One Volt SMARTMOS™ Rail–to–Rail Dual Operational Amplifier

MC33502D, P

 $T_A = -40^{\circ} \text{ to } +105^{\circ}\text{C}, \text{ Case } 751, 626$

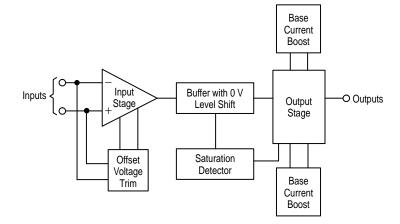
The MC33502 operational amplifier provides rail—to—rail operation on both the input and output. The output can swing within 50 mV of each rail. This rail—to—rail operation enables the user to make full use of the entire supply voltage range available. It is designed to work at very low supply voltages (1.0 V and ground), yet can operate with a supply of up to 7.0 V and ground. Output current boosting techniques provide high output current capability while keeping the drain current of the amplifier to a minimum.

- Low Voltage, Single Supply Operation (1.0 V and Ground to 7.0 V and Ground)
- High Input Impedance: Less than 40 fA Input Current
- Typical Unity Gain Bandwidth @ 5.0 V = 5.0 MHz,
 @ 1.0 V = 4.0 MHz
- High Output Current (I_{SC} = 50 mA @ 5.0 V, 10 mA @ 1.0 V)

- Output Voltage Swings within 50 mV of Both Rails
- Input Voltage Range Includes Both Supply Rails
- High Voltage Gain: 100 dB
- No Phase Reversal on the Output for Over–Driven Input Signals
- Input Offset Trimmed to <500 μV Typical
- Low Supply Current (ID = 1.2 mA, Typical)
- 600 Ω Drive Capability
- Extended Operating Temperature Range (-40° to 105°C)

APPLICATIONS

- Single Cell NiCd/Ni MH Powered Systems
- · Single Cell Lithium Powered Systems
- Portable Communication Devices
- Low Voltage Active Filters
- · General Systems Requiring Battery Power



High Frequency Amplifiers

A variety of high frequency circuits with features ranging from low cost simplicity to multifunction versatility marks Motorola's line of integrated amplifiers. Devices described here are intended for industrial and communications applications. For devices especially dedicated to consumer products, i.e., TV and entertainment radio. (See the Consumer Electronics Circuits section.)

AGC Amplifiers MC1490/MC1350 Family Wideband General Purpose Amplifiers

The MC1490 and MC1350 family are basic building blocks - AGC (Automatic Gain Controlled) RF/Video

Amplifiers. These parts are recommended for applications up through 70 MHz. The best high frequency performance may be obtained by using the physically smaller SOIC version (shorter leads) – MC1350D. There are currently no other RF ICs like these, because other manufacturers have dropped their copies. Applications include variable gain video and instrumentation amplifiers, IF (Intermediate Frequency) amplifiers for radio and TV receivers, and transmitter power output control. Many uses will be found in medical instrumentation, remote monitoring, video/graphics processing, and a variety of communications equipment. The family of parts using the same basic die (identical circuit with slightly different test parameters) is listed in the following table.

Table 4. High Frequency Amplifier Specifications

	rating ure Range	A _V (dB)	Bandwidth @ MHz		N _{EE} dc)	Suffix/
−40° to +85°C	0° to +70°C	Туј	oical	Minimum	Maximum	Package
_	MC1350	50	45	+6.0	+18	P/626, D/751
MC1490	-	50 45 35	10 60 100			P/626

Miscellaneous Amplifiers

Motorola provides several Bipolar and CMOS special purpose amplifiers which fill specific needs. These devices

range from low power CMOS programmable amplifiers and comparators to variable—gain bipolar power amplifiers.

MC3405
Dual Operational Amplifier and
Dual Voltage Comparator

This device contains two Differential Input Operational Amplifiers and two Comparators; each set capable of single supply operation. This operational amplifier—comparator circuit will find its applications as a general purpose product for automotive circuits and as an industrial "building block."

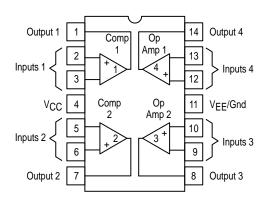


Table 5. Bipolar

	l _{IB} (μΑ)	V _{IO} (mV)	l _{IO} (nA)	A _{VOI} (V/mV)	Response	Supply Voltage		Suffix/
Device	(μΑ) Max	Max	Max	Min	(μs) Typ	Single	Dual	Package
MC3405	0.5	10	50	20	1.3	3.0 to 36	±1.5 to ±18	P/646

MC14573
Quad Programmable Operational Amplifier
MC14575
Dual Programmable Operational Amplifier and Dual Programmable Comparator

MC14576C/MC14577C Dual Video Amplifiers

Table 6. CMOS

Function	Quantity Per Package	Single Supply Voltage Range	Dual Supply Voltage Range	Frequency Range	Device	Suffix/ Package
Operational Amplifiers	4	3.0 to 15 V	±1.5 to ±7.5 V	DC to 1.0 MHz	MC14573	P/648, D/751B
Operational Amplifiers and Comparators	2 and 2	3.0 to 15 V	±1.5 to ±7.5 V	DC to 1.0 MHz	MC14575	P/648, D/751B
Video Amplifiers	2	5.0 to 12 V(1)	±2.5 to ±6.0 V(2)	Up to 10 MHz	MC14576C MC14577C	P/626, F/904

^{(1) 5.0} to 10 V for surface mount package.

⁽²⁾ ± 2.5 to ± 5.0 V for surface mount package.

Comparators

Table 7. Single Comparators

Device	l _{IB} (μΑ) Max	V _{IO} (mV) Max	liO (μΑ) Max	A _V (V/V) Typ	I _{IO} (mA) Min	Response Time (ns)	Supply Voltage (V)	Description	Temperature Range (°C)	Suffix/ Package
Bipolar										
LM211 LM311	0.1 0.25	3.0 7.5	0.01 0.05	200 k	8.0	200	+15, –15	With strobe, will operate from single supply	-25 to +85 0 to +70	D/751 N/626, D/751
CMOS								_		
MC14578	1.0 pA	50	Ī	_	1.1	_	3.5 to 14	Requires only 10 μA from single–ended supply	-30 to +70	P/648, D/751B

Table 8. Dual Comparators

Device	l _{IB} (μΑ) Max	V _{IO} (mV) Max	liO (μΑ) Max	A _V (V/V) Typ	I _{IO} (mA) Min	Response Time (ns)	Supply Voltage (V)	Description	Temperature Range (°C)	Suffix/ Package
Bipolar										
LM393 LM393A LM2903 LM2903V	0.25	5.0 2.0 7.0 7.0	0.05	200 k	6.0	1300 1300 1500 1500	±1.5 to ±18 or 3.0 to 36	Designed for single or split supply operation, input common mode includes ground (negative supply)	0 to +70 0 to +70 -40 to +105 -40 to +125	N/626, D/751
MC3405	0.5	10	0.05	200 k	6.0	1300	±1.5 to ±7.5 or 3.0 to 15	This device contains 2 op amps and 2 comparators in a single package	0 to +70	P/646
CMOS										
MC14575	0.001	30	0.0001	2.0 k	3.0	1000	±1.5 to ±7.5 or 3.0 to 15	This device contains 2 op amps and 2 comparators in a single package	-40 to +85	P/648, D/751B

Table 9. Quad Comparators

Device	l _{IB} (μΑ) Max	V _{IO} (mV) Max	l _{IO} (μΑ) Max	A _V (V/V) Typ	I _{IO} (mA) Min	Response Time (ns)	Supply Voltage (V)	Description	Temperature Range (°C)	Suffix/ Package
Bipolar										
LM239 LM239A LM339 LM339A LM2901 LM2901V MC3302	0.25	5.0 2.0 5.0 2.0 7.0 7.0 20	0.05	200 k 200 k 200 k 200 k 100 k 100 k	6.0	1300	±1.5 to ±18 or 3.0 to 36	Designed for single or split supply operation, input common mode includes ground (negative supply)	-25 to +85 -25 to +85 0 to +70 0 to +70 -40 to +85 -40 to +125 -40 to +85	N/646, D/751A P/646
CMOS										
MC14574	0.001	30	0.0001	2.0 k	3.0	1000	±1.5 to ±7.5 or 3.0 to 15	Externally programmable power dissipation with 1 or 2 resistors	-40 to +85	P/648, D/751B

Amplifiers and Comparators Package Overview



CASE 626 N, P, P1 SUFFIX



CASE 646 N, P SUFFIX



CASE 648, 648C DP2, P, P2 SUFFIX



CASE 751 D SUFFIX



CASE 751A D SUFFIX



CASE 751B D SUFFIX



CASE 751G DW SUFFIX



CASE 904 F SUFFIX

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